Product data sheet

1. General description

Silicon Carbide Schottky diode in a TO263 (D2PAK) plastic package, designed for high frequency switched-mode power supplies.





2. Features and benefits

- · Highly stable switching performance
- High forward surge capability I_{FSM}
- · Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- · Reduced losses in associated MOSFET
- Reduced EMI
- · Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
- · Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- · Motor Drives

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			6	50		V
$I_{F(AV)}$	average forward current	$δ$ = 0.5 ; square-wave pulse; T_{mb} ≤ 105 °C; Fig. 1; Fig. 2; Fig. 3	16			А	
Symbol	Parameter	Conditions	Min Typ Max		Max	Unit	
Static ch	aracteristics						
V_{F}	forward voltage	I _F = 16 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.5	1.7	V
		I _F = 16 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.8	2.1	V

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		K 14 A
2	K	cathode [1]		K A 001aaa020
3	Α	anode	i	
mb	К	mounting base; connected to cathode	1 3 TO-263 (D2PAK)	

^[1] It is not possible to connect to pin 2 of the TO263 package.

6. Ordering information

Table 3. Ordering information

Type number	Package	Orderable part number	Packing	Small packing	cking Package Pack	
	name		method	quantity	version	issue date
NXPSC16650B	TO263	NXPSC16650B6J	Reel	800	TO263N	26-Sep-2016

7. Marking

Table 4. Marking codes

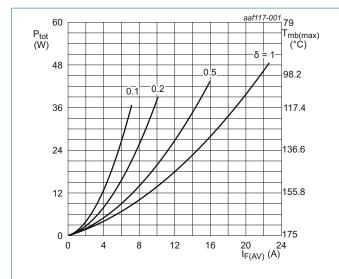
Type number	Marking codes
NXPSC16650B	NXPSC 16650B

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		650	V
V_{RWM}	crest working reverse voltage		650	V
V_R	reverse voltage	DC	650	V
I _{F(AV)}	average forward current	$δ$ = 0.5; square-wave pulse; $T_{mb} \le 105$ °C; Fig. 1; Fig. 2; Fig. 3	16	А
I _{FRM}	repetitive peak forward current	δ = 0.5; t_p = 25 μs; T_{mb} ≤ 105 °C; square-wave pulse	32	А
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	96	А
	forward current	t_p = 10 μs; $T_{j(init)}$ = 25 °C; square-wave pulse	770	А
l²t	I ² t for fusing	sine-wave pulse; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$	46	A ² s
T _{stg}	storage temperature		-55 to 175	°C
T _j	junction temperature		175	°C



$$\begin{split} & I_{\text{F(AV)}} = I_{\text{F(RMS)}} \times \sqrt{\delta} \\ & V_{\text{o}} = 0.767 \text{ V; R}_{\text{s}} = 0.0610 \text{ }\Omega \\ & \text{Fig. 1. Forward power dissipation as a function of average forward current; square waveform;} \end{split}$$

maximum values

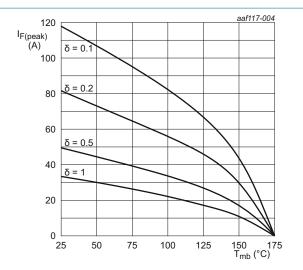
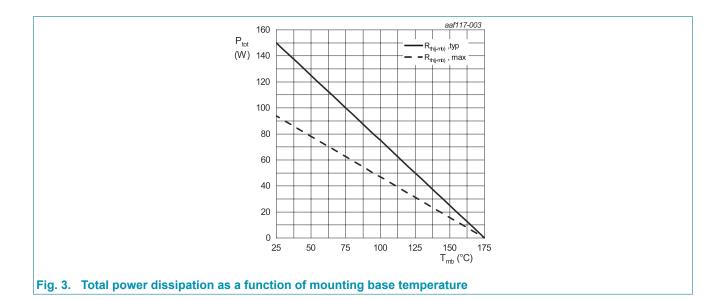


Fig. 2. Current derating as a function of mounting base temperature



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	with heatsink compound; Fig. 4	-	1	1.6	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

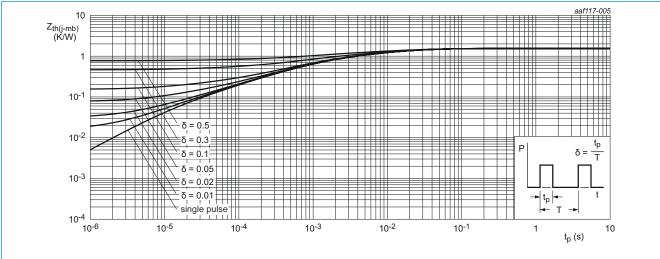
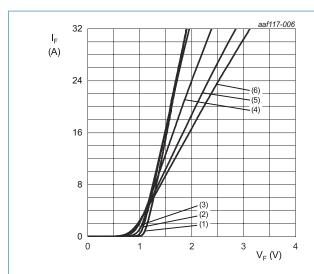


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

					1	
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V_{F}	forward current	I _F = 16 A; T _j = 25 °C; <u>Fig. 5</u>	-	1.5	1.7	V
		I _F = 16 A; T _j = 150 °C; <u>Fig. 5</u>	-	1.8	2.1	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C; <u>Fig. 6</u>	-	-	100	μA
		V _R = 650 V; T _j = 150 °C; <u>Fig. 6</u>	-	-	400	μA
Dynamic	characteristics				•	,
Q_r	recovered charge	$I_F = 16 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	26	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C	-	534	-	pF
		f = 1 MHz; V _R = 300 V; T _j = 25 °C	-	75	-	pF
		f = 1 MHz; V _R = 600 V; T _j = 25 °C	-	73	-	pF
E _{as}	non-repetitive avalanche energy	$I_R = 6.9 \text{ A}; L = 5 \text{ mH}; T_{j(init)} = 25 \text{ °C}$	120	-	-	mJ



 V_o = 0.767 V; R_s = 0.0610 Ω (1) T_i = -55 °C; typical values

(2) $T_j = 0$ °C; typical values (3) $T_i = 25$ °C; typical values

(4) $T_i = 100 \,^{\circ}\text{C}$; typical values

(5) $T_j = 150$ °C; typical values (6) $T_j = 175$ °C; typical values

Fig. 5. Forward current as a function of forward voltage; typical values

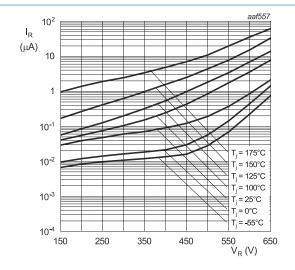
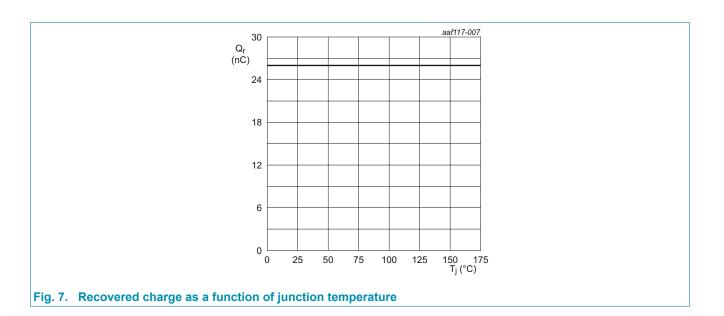
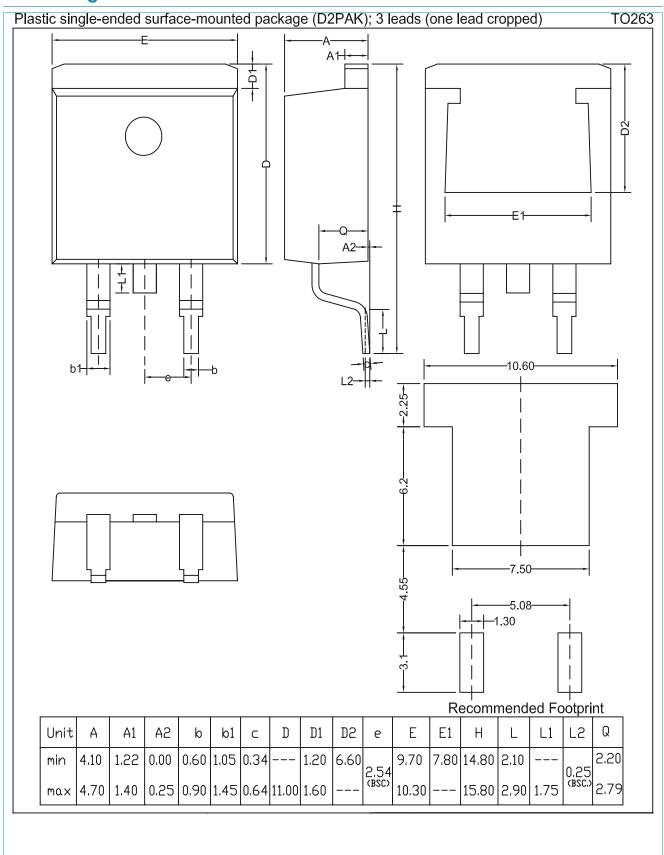


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value



11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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